RSC Advances



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Cite this: RSC Adv., 2024, 14, 21180

Spinel cobalt-based binary metal oxides as emerging materials for energy harvesting devices: synthesis, characterization and synchrotron radiation-enabled investigation[†]

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The synthesis and characterization of spinel cobalt-based metal oxides (MCo₂O₄) with varying 3d-transition metal ions (Ni, Fe, Cu, and Zn) were explored using a hydrothermal process (140 °C for two hours) to be used as alternative counter electrodes for Pt-free dye-sensitized solar cells (DSSCs). Scanning electron microscopy (SEM) and atomic force microscopy (AFM) revealed distinct morphologies for each metal oxide, such as NiCo₂O₄ nanosheets, Cu Co₂O₄ nanoleaves, Fe Co₂O₄ diamond-like, and Zn Co₂O₄ hexagonal-like structures. The X-ray diffraction analysis confirmed the cubic spinel structure for the prepared MCo₂O₄ films. The functional groups of MCo₂O₄ materials were recognized in metal oxides throughout Fourier transform infrared (FTIR) analysis. The local structure analysis using X-ray absorption fine structure (XAFS) at Fe and Co K-edge identified octahedral (Oh) Co^{3+} and tetrahedral (Td) Co^{2+} coordination, with Zn^{2+} and Cu^{2+} favoring Td sites, while Ni³⁺ and Fe³⁺ preferred Oh active sites. Further investigations utilizing the Fourier transformation (FT) analysis showed comparable coordination numbers and interatomic distances ranked as Co-Cu > Co-Fe > Zn-Co > Co-Ni. Furthermore, the utilization of MCo₂O₄ thin films as counter electrodes in DSSC fabrication showed promising results. Notably, solar cells based on $CuCo_2O_4$ and $ZnCo_2O_4$ counter electrodes showed 1.9% and 1.13% power conversion efficiency, respectively. These findings indicate the potential of employing these binary metal oxides for efficient and cost-effective photovoltaic device production.

Received 10th May 2024 Accepted 27th June 2024

DOI: 10.1039/d4ra03462g

rsc.li/rsc-advances

Introduction

Because of the permanent growth in the global population and industrialization, the demand for energy has increased steadily. Limits in fuel-based energy sources make the need for cleaner, sustainable alternative energy sources inevitable. Among all renewable energy sources, solar energy is one of the most impressive ones. Photovoltaic technologies, particularly dyesensitized solar cells (DSSCs), have emerged as key factors in this transition owing to their low cost and easy production processes. Another important parameter that increases the impression of DSSCs is the capability of harvesting energy from even lower-intensive light.

Significant effort has been devoted to increasing the power conversion efficiency and stability of DSSCs while making them cost-effective. To achieve optimal performance in the DSSCs, the counter electrode commonly incorporates platinum (Pt) on a surface of transparent conductive oxide.^{1,2} Several novel approaches have been formulated to improve the DSSCs' performance including enhancing the light absorption capacity of the sensitizer, charge separation of photo-induced charge at the electrolyte-semiconductor interface, and prompt the migration of charge towards the counter electrode.3-5 The proposed approaches involve the binding of a sensitizer onto wide bandgap semiconductor substrates such as titanium dioxide, which aims to enhance light absorption capabilities.6 Additional efforts have been made to replace the Pt counter electrode in DSSCs. As an alternative to Pt, various kinds of materials, including metal oxides, metal sulfides, carbon, and hybrid electrodes, have been proposed to obtain cost-effective

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[†] Electronic supplementary information (ESI) available. See DOI: https://doi.org/10.1039/d4ra03462g

Paper

device fabrication.⁷⁻¹¹ An alternative candidate with significant potential for DSSCs is spinel cobalt-based metal oxides (MB₂O₄, M: tetrahedral, B: octahedral sites). Such unique characteristics involve excellent electrical conductivity, efficient charge transfer, and significantly large surface area. Besides that, various oxidation states, and notable electrochemical activity make them highly advantageous to be used in energy and photocatalytic applications.¹²⁻¹⁵

The spinel cobalt oxide (Co₃O₄) is one of the most investigated electro-catalyst materials that is widely applied in the counter electrode for DSSCs. The tetrahedral site (Td) is occupied by Co^{2+} ions, while the octahedral site (Oh) is occupied by two Co³⁺ ions.¹⁶ To date, Co²⁺ and Co³⁺ serve as active sites within the spinel cobalt metal oxide Co₃O₄, and they have been reported to have a crucial role in charge transfer and their catalytic activity.¹⁷⁻¹⁹ Recent studies report that replacing the 3rd transition metal ions, such as Ni and Zn ions, with the Co²⁺ in spinel cobalt oxide (Co₃O₄) enhances their electrical conductivity.20 For instance, ZnCo2O4 and NiCo2O4 exhibited superior electrical conductivity compared to Co₃O₄. Zn²⁺ ions are beneficial for indicating defects in the Td sites.,17-20 as observed in spinel oxides, which in turn enhances the catalytic activity for the oxygen evolution reaction. Moreover, the large surface and electrical conductivity of NiCo2O4 result in better catalytic activity than spinel metal oxide (Co_3O_4) . Also, the Fe³⁺ in $FeCo_2O_4$ occupies the Oh sites, leading to a shift in energy level near the Fermi level, which improves the activity of spinel metal oxide.21,22

Several reports have integrated the spinel-based cobalt structure into DSSC devices. Interestingly, the Co₃O₄ counter electrode of PCE ~8.6% in DSSCs exhibits an excellent catalytic performance towards the iodide electrolyte compared to the Pt standard counter electrode.²³ It has been reported also that, Co₃O₄ has a good electro-catalytic activity towards reduction of I₃⁻ ions into I⁻ ions.²⁴ Furthermore, zinc substitution for Co in cobalt oxide(n,m) results in the spinel structure of Zn–Co–O with p-type conductivity. The hole transport layer of Zn–Co–O

employed in DSSCs results in enhanced diffusion length and transport within a device.²⁵ The DSSCs based spinel NiCo₂O₄ nanostructures reported high performance and are comparable to the Pt counter electrode.²⁶ To address, the role of the local structure of the spinel-based cobalt materials in DSSCs performance still needs in-depth investigation.

In the present work, three-dimensionally arrays of spinel cobalt-based metal oxide thin films of MCo_2O_4 (M: Ni, Fe, Cu, Zn) were fabricated through hydrothermal deposition to use them as counter electrodes to obtain cost-effective DSSCs. Surface morphology and roughness of the prepared samples were investigated throughout SEM and AFM analysis. The XAFS technique is employed to examine the atomic coordination and interatomic distances by observing the local structure at Fe and Co K-edge. Also, the XANES spectra indicate the prepared samples have a spinel structure. Then, spinel cobalt-based metal oxide thin films were used in the fabrication of DSSCs as promising counter electrodes, and the photovoltaic performance of DSSCs with MCo_2O_4 counter electrodes were compared.

Experimental procedures

The following materials are used to synthesis the spinel cobalt based oxide films: copper nitrate tetrahydrate (Cu(NO₃)₂·4H₂O), iron monohydrate (Fe(NO₃)₂·H₂O), nickel nitrate hexahydrate (Ni(NO₃)₂·6H₂O), and zinc nitrate hexahydrate (Zn(NO₃)₂· ·6H₂O), cobalt nitrate hexahydrate (Co(NO₃)₂·6H₂O), hexamethylenetetramine (HMTA, (CH₄)₆N₄), and indium tin oxide (ITO) coated glasses, all are purchased from Sigma Aldrich and used without any further purification.

The samples were grown hydrothermally using a solution processing route. The synthesis of spinel cobalt-based metal oxide thin films, MCo₂O₄, coated over a cleaned ITO substrate is shown in Fig. 1. The ITO substrate was subjected to cleaning in the acetone for 15 min followed by 15 min in the ethanol under sonication. The preparation procedure was performed by



Fig. 1 A schematic illustration depicting the deposition procedures of spinel cobalt-based samples.

mixing 0.1 M of $M(NO_3)_2 \cdot xH_2O$ dissolved in 40 mL deionized water, and 0.1 M of $Co(NO_3)_2 \cdot 6H_2O$ dissolved in 40 mL deionized (DI) water. The solution was then stirred at 400 rpm for 30 min. Then, the 0.1 M of $(CH_2)_6N_4$ was added to the prepared aqueous solution. The obtained stock solutions were then transferred into a glass-sealed bottle containing a cleaned ITO substrate before being grown in an oven at 140 °C for two hours. Finally, the deposited spinel cobalt-based metal oxides of MCo_2O_4 films were rinsed with deionized water and annealed at 400 °C in a furnace for another two hours.

Scanning electron microscopy (SEM, Quanta FEG 450) was conducted to investigate the morphology and size distribution of the metal oxide samples. The surface roughness of the MCo₂O₄ thin films was carried out by using an atomic force microscope (AFM, SmartSPM[™] 1000), FTIR (Bruker Vertex 80 and Hyperion 2000 microscope) used to investigate the vibrational modes and chemical bonds of metal oxides. The XAFS data were obtained via the BM-08 XAFS/XRF beamline at the Synchrotron-Light for Experimental Science and Applications in the Middle East (SESAME). The beamline was run in decay condition at an energy level of 2.5 GeV, with 300 mA as a maximum current. The X-ray absorption fine structure (XAFS) data were measured on the BM08-XAFS/XRF beamline of the SESAME operated at 2.5 GeV in "decay" mode with a maximum electron current of 300 mA.27 The XAFS spectra of the materials were acquired in transmission mode in the spectral range of Co K-edge (7709 eV) and Fe K-edge (7112 eV) at room temperature. The X-ray beam intensity was measured by ionization chambers filled with an optimal mixture of noble gases at a total pressure of 1.0 bar, and the XAFS data of the samples were acquired from the signals measured at ion chambers subsequently amplified by Stanford picoammeters and digitalized by a voltage to frequency converter, using a double-crystal Si (111) monochromator. The energy was calibrated at the Co K-edge (7709 eV)

and Fe K-edge (7112 eV) of the Co and Fe standard metal foils, respectively. The sample was prepared in pallet form (13 mm diameter) by pressing a homogeneous mixture of calculated quantity of finely ground material and polyvinylpyrrolidone (PVP) powder. The amount of material in the pellet was calculated using XAFS mass software to give an absorption $\mu t \sim 1.5$, just above the Co K-edge and Fe–K edge absorptions.

The DSSCs were prepared using TiO₂ nanoparticle decorated ITO coated photoanodes. The electrodes were sintered at 450 °C in air ambient for 30 min to remove contaminations from the TiO₂ nanoparticle surfaces. And then was immersed in N719 dye for a night. The photoanodes were washed with ethanol and dried using a heat gun. MCo_2O_4 coated ITO counter electrodes and dye-coated TiO₂ photoanodes were sealed together and an electrolyte (iodide/tri-iodide in a nitrile solvent) was used to fill the space between two electrodes. The performances of DSSCs were measured under a class A solar simulator (ABET Technology Sun2000) with an AM 1.5 G filter and 100 mW cm⁻² light intensity using a Keithley 2425 source meter.

Results and discussion

The DSSCs device performance is directly influenced by the morphology of the counter electrode in particular redox/ oxidation electrolyte at the interface. SEM images can give insight into crystal arrays and defective surfaces of spinel cobalt oxides. The surface morphologies of as-prepared MCo_2O_4 thin films are illustrated in Fig. 2. Interestingly, the morphology of the prepared samples can be correlated to the variations in source metal ions. Fig. 2(a) and (b) manifested uniform arrays of nano-leave structures that coincide with the $CuCo_2O_4$ thin film. Whereas Fig. 2(c) and (d) displays uniform arrays of octahedral-shaped structures observed in the $FeCo_2O_4$ thin film. The $FeCo_2O_4$ thin film is comprised of nano-blocks with average size of about 500 nm. The observed octahedron structure



Fig. 2 SEM images of the obtained (a and b) CuCo₂O₄ thin film (c and d) FeCo₂O₄ thin film (e and f) NiCo₂O₄ thin film and (g and h) ZnCo₂O₄ thin film.

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demonstrates high-pressure conditions controlled by the (111) plane, devoid of any preferential axis for selective growth.²⁸ Fig. 2(e) and (f) displays a hierarchical structure of NiCo₂O₄ nano-sheets observed with hollow arrays. Fig. 2(g) and (h) depicts a twin hexagonal configuration of nano-block ZnCo₂O₄ arrays observed with non-uniform distribution due to anisotropic growth along [100] and [001] directions.²⁹ It is impressive to find that different Zn²⁺, Fe²⁺, Ni²⁺, and Cu²⁺ reacted species tend to form spinel structures in a cubic crystal phase. The intricate reaction pathways of these species during the hydrothermal process drive the formation of distinct morphologies of spinel metal oxides. Initially, the decomposed reacted species undergo a recrystallization process to form MCo₂O₄ with preferential growth on selective planes, depending on the nature of the ions. The synthesis of MCo₂O₄ is driven by the formation of $M(OH)_2$ and $Co(OH)_2$ before transforming into $MCo_2(OH)_6$ complex compound, as demonstrated by the NR Chodankar group.³⁰ Alternatively, another reaction route suggests that the formation pathway is governed by the formation of Co₃O₄ and MO, which are then reduced to the MCo₂O₄ structure.³¹ The annealing process reduces the OH- ions in the complex compound to the oxide form, resulting in the obtaining of bimetal oxides.

The HMT acts as an alkaline source that assists in the formation of M-Co precursor. During the hydrolysis of HMT, NH₃ is released, making the solution alkaline. This process also produces OH⁻ ions in the hydrothermal synthesis, which react with Zn^{2+} , Fe^{2+} , Ni²⁺, Cu^{2+} , and Co^{2+} ions to form spinel metal oxide. Furthermore, studies have found HMT useful for obtaining a crystalline spinel metal oxide structure. The alkaline environment facilitated by HMT is preferable for precipitating M^{2+} and Co^{2+} ions during hydrothermal deposition, accelerating the formation of the crystalline MCo₂O₄ structure.^{32,33}

The surface area and roughness of the electrodes can provide significant insight into understanding the charge transfer



Fig. 3 AFM images of as-deposited metal oxides of NiCo₂O₄, CuCo₂O₄, ZnCo₂O₄, NiCo₂O₄, and FeCo₂O₄ in 2D and 3D profile.

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mechanism and overall device performance. The AFM imaging was performed for the MCo_2O_4 thin films and illustrated in Fig. 3. The AFM images of the prepared $CuCo_2O_4$ thin film exhibit a high root mean square (RMS) roughness of 0.16 µm and a large surface area of 38.74 µm². While the FeCo₂O₄ thin films show a polygon-shaped structure with an overall RMS of 0.03 µm and a surface area of 29.9 µm². The phase image demonstrates a variation between – 50° and 20° indicating low phase separation at the grain boundaries. The NiCo₂O₄ nanosheets thin films depict a large surface area of 58.87 µm² and RMS of 0.26 µm with an average thickness of nearly 20 nm, while a high roughness was observed for the hexagonal structure of $ZnCo_2O_4$ with an RMS of 0.35 µm and surface area of 34.9 µm². The hexagonal plates of $ZnCo_2O_4$ are stacked in a non-uniform structural array.

In DSSCs, the device performance is highly dependent on the crystal quality of the counter electrode based a binary metal oxide films. The cubic spinel structure was confirmed for various metal oxide films from crystallographic X-ray diffraction plots in Fig. S1.[†] As seen, the diffracted XRD peaks of FeCo₂O₄ film match the (220), (311), (400), (422), and (440) crystal planes indexed to Fd3m space group (JCPDS card No. 04-0850). The crystal profile of $NiCo_2O_4$ nano-sheets assigned to (111), (220), (311), (222), (400), (331), and (511) crystal planes suggested Fd3m space group (JCPDS card No. 01-073-1702). For CuCo₂O₄ nano-leaves, the observed XRD profile in agreement with (111), (220), (311), (400), (422), and (511) crystallographic planes analogue to Fd3m space group (JCPDS card No. 23-1390). The ZnCo₂O₄ tends to form a crystal structure throughout hydrothermal synthesis similar to the above metal oxide films. The crystal diffraction profile of $ZnCo_2O_4$ resembles (220), (311), (222), (511), and (620) crystal planes for *Fd3m* (227) space group (JCDP card No. 00-001-1149).

The UV-vis-NIR spectral of the spinel metal oxide films plots in Fig. S2[†] and the corresponding extrapolated absorption band gap energies (E_{α}) were determined according to Tauc plot. The NiCo₂O₄ nanosheets exhibit higher absorbance compared to the other spinel materials oxides followed by crystal CuCo2O4 nanoleaves. The straight-line interception yields two band gap energies of 1.98 and 2.50 eV for ZnCo₂O₄, while the obtained band gap energies of 2.00 and 3.35 eV for NiCo2O4 in agreement with the reported values of 2.00 and 3.30 eV.34 The valence band in NiCo2O4 was constructed from O 2p orbital and the conduction band from 3d orbitals of Ni and Co. And has an electron configuration of tetrahedral high spin Co^{2+} (eg⁴ t₂g³), octahedral low spin $\text{Co}^{3+}(t_2g^6)$, and $\text{Ni}^{3+}(t_2g^6\text{e}g^1)$. Therefore, the electron can be excited from Co-3d-t2g to the partially filled Co 3d-eg orbital. Consequently, the presence of two band gap energies can be assigned to high spin and low spin of Co³⁺ in the spinel structure.³⁴ The spinel CuCo₂O₄ band gap energies was 1.88 eV and 3.0 eV and FeCo₂O₄ yields 2.18 eV and 2.82 eV. The determined values are close to those reported in the literature.35,36

The solution processed DSSCs device *via* hydrothermal usually contains –OH functional group. To verify the presence of the –OH group and other functional groups that could influence the device performance, the FTIR profile illustrated in Fig. 4



Fig. 4 FTIR profile of the prepared binary metal oxide films MCo_2O_4 .

corresponds to the prepared MCo_2O_4 films. The vibration modes that match the M–O group can be seen at 584.3 cm⁻¹ in various sample profiles. The M–O vibration modes at 584.3 cm⁻¹ and 700 cm⁻¹ may be associated with octahedral and tetrahedral sites.³⁷ Furthermore, stretching modes located at approximately 882 cm⁻¹ and 1000 cm⁻¹ are assigned to the C–O group. Furthermore, the weak vibrational mode at 1277.8 cm⁻¹ and 1299.1 cm⁻¹ is linked to the NO₃⁻ group.³⁸ Additional stretching characteristics identified at 1598.8 cm⁻¹ and 1600 cm⁻¹ were assigned to COO and C=O molecules.³⁹ The stretching modes at 2931.7 cm⁻¹, 2936.8 cm⁻¹, 3785.8 cm⁻¹, and 3795.8 cm⁻¹ are attributed to the O–H functional group.^{40,41} A higher content of OH– molecules was noticed in the case of ZnCo₂O₄ associated with a prominent shift in the OH vibration mode.

The local structure of the MCo₂O₄ thin films could play an effective role in the DSSC device performance. The applied XAFS integrates to resolve the local structure of spinel cobalt oxide devices. The XANES spectra at Co absorption K-edge are presented in Fig. 5 of the prepared samples. Resolving the FeCo₂O₄ structure at the Co absorption K-edge is elusive and therefore XANES is applied at the Fe absorption K-edge was (7722.53 eV) for NiCo₂O₄, (7724.02 eV) for CuCo₂O₄ and (7722.18 eV) for ZnCo₂O₄. The observed Co absorption K-edge aligns with the value reported in the literature at 7721.4 eV, while the Fe absorption K-edge was 7125.53 eV for FeCo₂O₄. The oxidation state of the cobalt cation is Co³⁺ and the observed XANES spectrum reveals the spinel structure of the prepared samples.^{42,43}

The observed XANES spectrum reveals a low-intensity preedge peak at A, which can be assigned to $1s \rightarrow 3d$ quadrupole transition in spinel cobalt oxide (Co₃O₄).⁴⁴ A transition edge (shoulder region) was observed at B, along with the prominent white-line peak of high intensity at C. These transition edges at



Fig. 5 XANES spectra collected at Fe and Co K-edge of (a) NiCo₂O₄, (b) ZnCo₂O₄, and (c) CuCo₂O₄ collected at Co K-edge and (d) FeCo₂O₄ collected at Fe kedge; inset figures illustrate the corresponding first derivative of the absorption spectra.

B and C can be attributed to resonance peaks.^{45,46} The white-line region can be ascribed to the 1s \rightarrow np transition.⁴⁶

Following that, minor peaks of low intensity were observed at D and E. The broadening of peak D, in particular, in $FeCo_2O_4$ can be attributed to the coordination atoms in the vicinity of the Co absorber atom. Moreover, two peaks at E and F indicate the presence of multiple scattering associated with the coordination of the medium-range structure surrounding the Co absorber atom.^{47,48} Furthermore, two peaks at G and H were observed in the XANES spectrum coinciding with the $ZnCo_2O_4$ sample, which can be attributed to the existence of multi-scattering effects.

To facilitate a comprehensive quantitative analysis of the local atomic structure of the MCo₂O₄ nanomaterials, the EXAFS fitting in R-space was conducted.⁴⁹ The experimental EXAFS data in R-space in the range of 1.0 to 5.0 (Å) with Hanning window and k range of 3.0 Å⁻¹ were analyzed to the best fit. The initial four high-ranking single scattering paths of Co–O and M–Co bond pairs were included in the fit. The passive electrons reduction factor S_0^2 and energy shift E_0 were set similarly for all the paths in the fit, and the mean-square relative displacement σ^2 and interatomic distance *R* were refined relatively to get the best fit result.

Fig. 6 plots k^3 -weighted EXAFS with the best fit, and the FT, respectively. The fit parameters with details are listed in Table 1. The FT analysis of spinel FeCo₂O₄ structure shows a strong peak around 1.500 Å assigned to the Fe–O₁ (2.239 Å) coincides with T_d Fe²⁺ and Fe–O₂ (1.963 Å) assigned to O_h Fe³⁺. The Fe–Co₁ and Fe–Fe₁ bonds are observed near the 3 Å which reveals the Co²⁺ cations are substituted by Fe²⁺ cations in the spinel Co₃O₄ structure (FeCo₂O₄). The Fe–Co¹ can be resolved to O_h Fe³⁺ and

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Fig. 6 k^3 -weighted EXAFS data with the best fit from Co and Fe K-edge absorption, FT, and the Re (FT) of the EXAFS data, respectively for (a-c) FeCo₂O₄, (d-f) ZnCo₂O₄, (g-i) Cu Co₂O₄ and (j-l) NiCo₂O₄ samples.

 $T_d Co^{2+}$ sites. According to the reported data, the Fe, Cu, and Ni cations exhibit a tendency to occupy the octahedral sites (O_h) and leave tetrahedral (T_d) sites in spinel Co₃O₄.⁵⁰ On the other side, the Co²⁺ ions in the Co₃O₄ compound are substituted by Zn²⁺ ions, which exhibit tetrahedral symmetry (T_d), leading to the formation of ZnCo₂O₄.⁴⁶ Interestingly, the ZnCo₂O₄ tends to form a spinel structure as the Zn²⁺ occupy the tetrahedral sites (T_d) and leaving the Co³⁺ at octahedral sites (O_h).⁵¹ The crystal ZnCo₂O₄ has a spinel structure (A²⁺Co₂³⁺O₄, where, A is tetrahedral and B is octahedral sites) closely similar to the Co₃O₄ structure.⁵¹ Indeed, the FT shows Co–O₁ (1.966 Å) interaction, which is characteristic of O_h Co³⁺. Also, the Co–Zn₁ bond suggested T_d Zn²⁺ and O_h Co³⁺ in the spinel structure of ZnCo₂O₄.

confirmed the CoO₆ structure has octahedral symmetry, whereas the CoO₄ exhibits tetrahedral symmetry.⁵² Furthermore, the results imply that the Zn²⁺ cations have a tendency to occupy active sites characterized by a low oxidation state, whereas Co³⁺ cations are left in octahedral locations. It is clear that T_d Zn²⁺ and O_h Co³⁺ ions were presented in the crystalline structure of the ZnCo₂O₄ spinel structure.

Moreover, the FT first peak at 1.900 Å interatomic distance in spinel CuCo₂O₄ structure corresponds to the Co–O₁ (1.917 Å) of Oh Co³⁺ and Co–O₂ (2.058 Å) of T_d Co²⁺. The results in accordance with the previous reports.^{51,53} The FT peak at 3.200 Å is correlated to Co–Co₁ (3.237 Å) and Co–Cu1 (3.462 Å) bond interactions. It has been reported that the Co–Co interactions can be found in Oh and Td as Co³⁺–Co³⁺ (2.85 Å), Co³⁺–Co²⁺ (3.346 Å), and Co²⁺–Co²⁺(3.495 Å).⁵⁴ Therefore, the Co–Co1

Table 1 EXAFS fitting parameters, including coordination number (*N*), mean coordination shell radii (*R*), mean square relative displacements (MSRDs) or Debye–Waller factor (σ^2), amplitude reduction factor (S_o^2), photoelectron energy (E_o) and goodness of the fit (R_{factor}) for the MCo₂O₄ binary metal oxides

Sample	Bond type	N	R (Å)	σ^2 (Å ²)	S_0^2	$E_{\rm o}$ (eV)	R _{factor}
CuCo ₂ O ₄	Co-O ₁	2	1.917 ± 0.010	0.0023 ± 0.0044	1	0.530	0.1057
	Co-O ₂	2	2.058 ± 0.091	0.0147 ± 0.0423	1	0.530	0.1057
	Co-Co ₁	2	3.237 ± 0.150	0.0094 ± 0.0057	1	0.530	0.1057
	Co-Cu ₁	4	3.462 ± 0.067	0.0066 ± 0.0087	1	0.530	0.1057
NiCo ₂ O ₄	Co-O ₁	2	1.912 ± 0.017	0.0009 ± 0.0020	1	0.679	0.0103
	Co-O ₂	4	1.940 ± 0.174	0.0238 ± 0.0072	1	0.679	0.0103
	Co-Ni ₁	4	2.835 ± 0.042	0.0037 ± 0.0088	1	0.679	0.0103
	Co-Co ₁	2	2.988 ± 0.078	-0.0015 ± 0.0099	1	0.679	0.0103
ZnCo ₂ O ₄	Co-O ₁	4	1.966 ± 0.036	0.0045 ± 0.0023	1	0.250	0.0571
	Co-O ₂	6	3.808 ± 0.166	0.0045 ± 0.0268	1	0.250	0.0571
	Co-Zn ₁	4	3.197 ± 0.058	0.0057 ± 0.0038	1	0.250	0.0571
	Co-Co ₁	6	3.439 ± 0.234	0.0001 ± 0.0303	1	0.250	0.0571
FeCo ₂ O ₄	Fe-O ₁	2	2.239 ± 0.173	0.0056 ± 0.027	1	0.527	0.0320
	Fe-O ₂	4	1.963 ± 0.105	0.0045 ± 0.0054	1	0.527	0.0320
	Fe-Co ₁	4	3.224 ± 0.252	0.0006 ± 0.0123	1	0.527	0.0320
	Fe-Fe ₁	2	3.409 ± 0.266	-0.0015 ± 0.012	1	0.527	0.0320

interactions in spinel CuCo₂O₄ assigned to O_h Co³⁺ and T_d Co²⁺. Moreover, the Co–Cu₁ bridges the T_d Cu²⁺ and T_d Co²⁺.

The above-reported XANES (Fig. 5b) pre-edge of NiCo₂O₄ suggested the presence of T_d Co²⁺ symmetry.⁵⁵ It can be preliminary concluded that, the NiCo₂O₄ is close to the spinel Co₃O₄ structure and the oxidation state for both is 8/3 as oxidation state corresponding to the presence of O_h Ni³⁺.56 The FT analysis of NiCo₂O₄ reveals a peak at the lowest interatomic distance of 1.94 Å assigned to Co-O₁ of O_h (Co³⁺O₆) and Co-O₂ of T_d (Co²⁺O₄).⁵⁷ The next FT peak at 2.9 Å corresponds to Co-Co₁ (2.988 Å) and 4Co-Ni₁ (2.835 Å) interactions. It's evident the Co-Co₁ is characteristic of Oh Co³⁺ and the Co-Ni1 coincides characteristic of $O_h \operatorname{Co}^{3+}$ and the Co–Ni₁ coincides with $O_h \operatorname{Co}^{3+}$ and O_h Ni³⁺. In general, the Co-O interatomic distances at T_d or Oh sites are shorter than M-O distances which is correlated with a small atomic radius of Co^{3+} in comparison with M^{2+} . It is obvious that the Co-O1 and Co-O2 in ZnCo2O4 are longer compared to other spinel structures. It is worth noting that, the interatomic distances of M-Co introduced in Table 1 are observed as Co-Cu > Co-Fe > Zn-Co > Co-Ni.

The working mechanism of DSSCs in this study, as illustrated in Fig. 7, involves several key components and processes.





Fig. 7 Schematic diagram of MCo_2O_4 counter-electrode-based DSSC.



Fig. 8 Current density–voltage plots of DSSCs formed using Pt and $\text{MnCo}_2\text{O}_4\text{-}\text{based}$ counter electrodes.

DSSCs	$J_{ m max}~ m mA~cm^{-2}$	V _{max} mV	$J_{ m sc}~ m mA~cm^{-2}$	V _{oc} mV	FF	PCE %
CuCo ₂ O ₄	4.23	550	4.80	705.8	56.1	1.90
FeCo ₂ O ₄	0.99	150	1.96	401.8	18.8	0.15
NiCo ₂ O ₄	1.67	160	3.25	364.9	22.6	0.27
ZnCo ₂ O ₄	2.83	400	3.41	642.0	51.7	1.13
Pt	10.81	440	12.1	664.1	59.2	4.76

Fig. 8 shows current density-voltage (I-V) plots of the DSSCs fabricated using sensitized MCo₂O₄ based counter electrodes in comparison with Pt-based one as reference solar cell under illumination of 100 mW cm⁻². Table 2 summarizes the obtained results and highlights significant differences among the examined thin films. As presented in Table 2, the DSSC with a counter electrode based on CuCo2O4 nano-leave gives the best photovoltaic response with a J_{max} of 4.23 mA cm⁻² and a V_{max} of 550 mV which results in 1.9% power conversion efficiency. It is also seen that the open circuit voltage (V_{OC}) value of this device (705.8 mV) superior to the one for conventional DSSC with Pt electrode (664.1 mV). The second-best solar cell efficiency is reported as 1.13% for the DSSC obtained using ZnCo₂O₄ hexagonal-like structures. The $V_{\rm OC}$ value of this device with 642.0 mV is very close to the cell with Pt electrode. The other two solar cells obtained from NiCo2O4 nanosheets and FeCo2O4 diamond-like structures have lower PCE values of 0.27 and 0.15%, respectively. The lower short-circuit current density (I_{SC}) values observed in our study for DSSCs utilizing alternative counter electrodes, such as CuCo2O4, FeCo2O4, NiCo2O4, and ZnCo₂O₄, compared to conventional Pt-based DSSCs. It suggests potential limitations in transport mechanisms associated with these materials. Factors such as differences in catalytic activity, electronic structure, and surface morphology may contribute to the reduced efficiency of photogenerated charge carriers and subsequent lower J_{SC} values. Similar studies have been performed for various metal oxides including binary metal oxides.58-60 For instance, Kaya et al. hydrothermally sensitized CuCrO₂ delofossite oxide nanoparticles to use them as photocathode in the fabrication of high efficient tandem p-n photoelectrochemical cells using CuCrO2 delafossite semiconductors as photocathodes coupling with traditional n-type TiO₂ based photoanodes.⁵⁹ They reported the efficiency of solar cells between 1.67 and 2.33% for various annealing temperatures.

Considering the structural properties examined in this study across various spinel metal oxides, the samples consistently demonstrated high crystallinity, primarily in the cubic phase. Notably, the identification of active structural planes in these samples indicates a correlation between electrochemical activity and charge injection with these specific planes. For instance, the (311) plane was prominent in the $ZnCo_2O_4$ structure, the (220) plane in $CuCo_2O_4$, both (311) and (220) planes in Ni Co_2O_4 , and the (220) plane in $FeCo_2O_4$. Furthermore, distinctive characteristics and morphologies were observed in the hexagonal structure of $ZnCo_2O_4$ and the nanosheet morphology of $CuCo_2O_4$, which are thought to enhance the photocurrent and efficiency of DSSCs.

Conclusions

The spinel cobalt-based metal oxides of MCo₂O₄ (M: Ni, Cu, Fe, or Zn), were synthesized through the hydrothermal growth technique on ITO substrate to use them as counter electrodes in the fabrication of Pt free DSSCs. The oxides displayed a uniform and homogeneous surface morphology. Interestingly, NiCo₂O₄ exhibits nanosheets, Fe Co2O4 displays diamond shapes, CuCo₂O₄ shows nanoleaves, and ZnCo₂O₄ presents a hexagonal shape. These morphologies exhibit unique structural features characterized by a significantly large surface area and the existence of surface defect sites to enhance chemical reactivity. To probe the local structure of the prepared samples, EXAFS data was carried out at Fe and Co K-edge. The absorption Co K-edge was close to the 7721.4 eV value reported in the literature. The Fe Kedge was 7125.53 eV for FeCo₂O₄. The pre-edge peak in XANES of the prepared samples suggested $T_d Co^{2+}$. The shape of the XANES spectrum reveals the spinel structure of the obtained samples. The FT reveals a Co-O₁ coincides with O_h Co³⁺ and Co-O₂ is characteristic for T_d Co²⁺. On the contrary, Fe-O₁ reveals T_d Fe²⁺ and Fe–O₂ associated with O_h Fe³⁺. The interatomic distances evaluated from FT analysis of M-Co were observed as Co-Cu > Co-Fe > Zn-Co > Co-Ni. In addition, it is reported that these spinels cobalt-based binary metal oxides, especially CuCo₂O₄ nanoleaves and ZnCo₂O₄ hexagonal-like structures are promising candidates for the low cost and high efficient DSSCs with 1.9 and 1.13% power conversion efficiency values, respectively.

Data availability

The data that support the findings of this study are available from the corresponding author, Bashar Aljawrneh, upon reasonable request. Researchers interested in accessing the data should contact Bashar Aljawrneh at b.aljawarneh@zuj.edu.jo.

Author contributions

Abdelelah Alshanableh: conceptualization, investigation, methodology, data curation, writing – original draft, writing – review & editing. Yusuf Selim Ocak: conceptualization, investigation, methodology, data curation, writing – original draft, writing – review & editing. Bashar Aljawrneh: conceptualization, investigation, methodology, data curation, writing – original draft, writing – review & editing. Borhan Aldeen Albiss: supervision, investigation, review & editing, funding acquisition. Khaled Shawakfeh: supervision, investigation, review & editing, funding acquisition. Latif U. Khane: investigation, methodology, data curation, writing – original draft. Messaoud Harfouchee: investigation, methodology, data curation, writing – original draft. Saja Alrousan: investigation, methodology, data curation.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

This work supported by Jordan University of Science and Technology (JUST) under grants No. 135/2023 and 148/2022.

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